

1 93. The device of claim 76, wherein said plurality of layers of semiconductor material with
2 different optical indices are made in the $\text{Al}_x\text{Ga}_y\text{In}_{1-x-y}\text{N}$ semiconductor system on a SiC
3 substrate.

1 94. The device of claim 76, wherein said plurality of layers of semiconductor material with
2 different optical indices are made in a the $\text{Al}_x\text{Ga}_y\text{In}_{1-x-y}\text{As}_z\text{N}_{1-z}$ semiconductor systems on a
3 GaAs substrate.

1 95. The device of claim 76 wherein said plurality of layers of semiconductor material with
2 different optical indices are made of II-VI compound semiconductors.

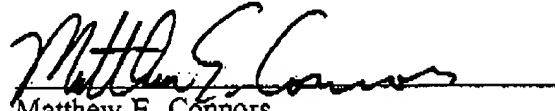
1 96. The device of claim 76 wherein said plurality of layers of semiconductor material with
2 different optical indices are made of IV-VI compound semiconductors.

RESPONSE

In response to the Restriction Requirement of November 5, 2002, Applicant elects species 12, drawn to claims 13-18 and 20-27. These claims are generic because they read upon all the alleged species. Furthermore, claims 56-96 are also generic because they also read upon all the alleged species.

Examination on the merits is respectfully requested.

Respectfully submitted,



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